

2SC5850

Silicon NPN Epitaxial

REJ03G0760-0100
(Previous ADE-208-1479)

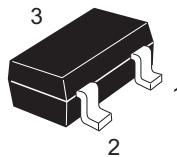
Rev.1.00

Aug.10.2005

Features

Low frequency amplifier

Outline

RENESAS Package code: PTSP0003ZA-A
(Package name: CMPAK[®])

1. Emitter
2. Base
3. Collector

*CMPAK is a trademark of Renesas Technology Corp.

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	50	V
Collector to emitter voltage	V_{CEO}	40	V
Emitter to base voltage	V_{EBO}	5	V
Collector current	I_C	100	mA
Emitter current	I_E	-100	mA
Collector power dissipation	P_C^*	150	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 to +125	°C

*Value on the glass epoxy board (10 mm x 10 mm x 0.7 mm)

Electrical Characteristics

(Ta = 25°C)

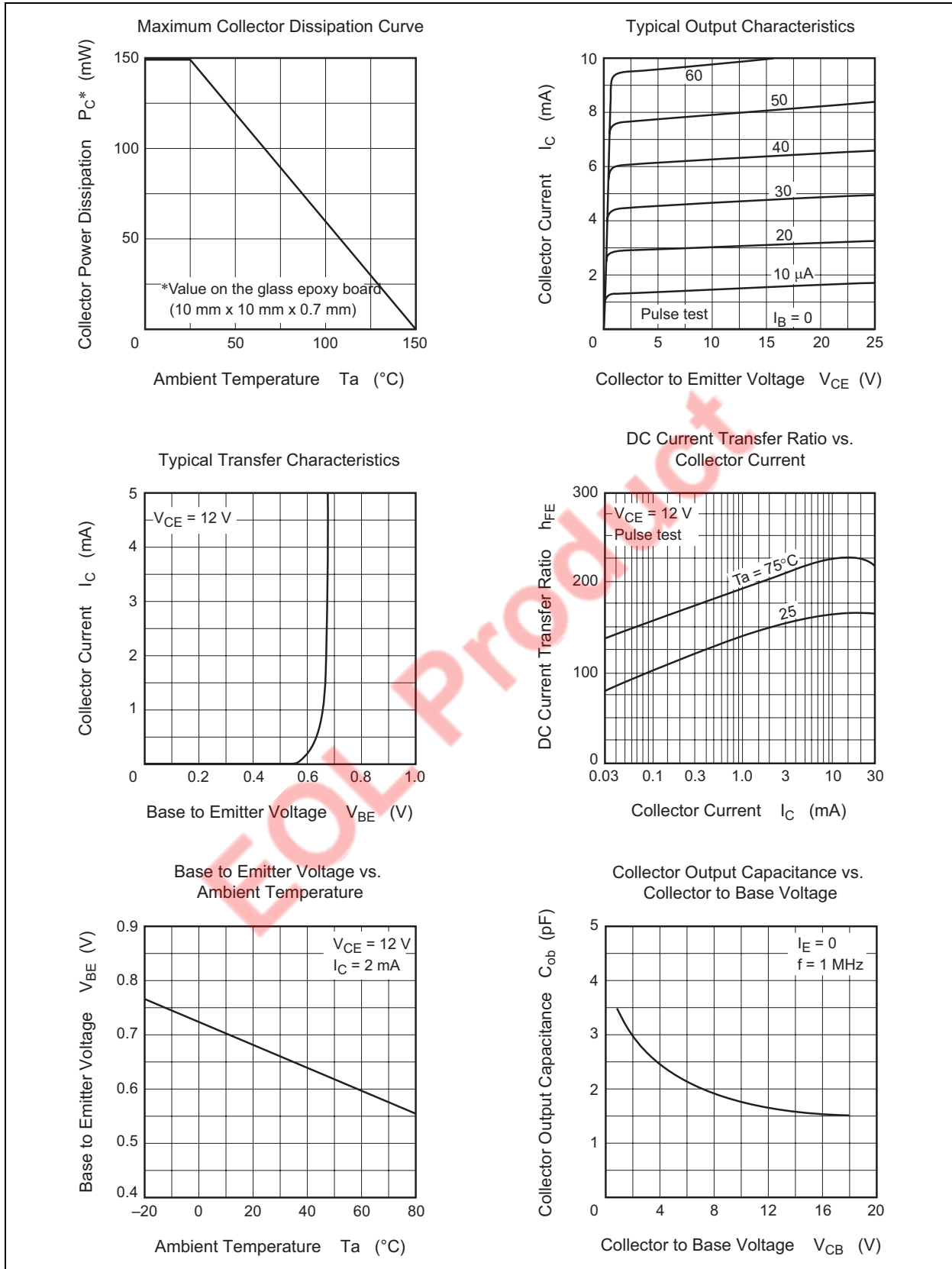
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	50	—	—	V	$I_C = 10 \mu A, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	40	—	—	V	$I_C = 1 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	—	—	V	$I_E = 10 \mu A, I_C = 0$
Collector cutoff current	I_{CBO}	—	—	0.5	μA	$V_{CB} = 30 \text{ V}, I_E = 0$
Emitter cutoff current	I_{EBO}	—	—	0.5	μA	$V_{EB} = 2 \text{ V}, I_C = 0$
DC current transfer ratio	h_{FE}^{*1}	100	—	500		$V_{CE} = 12 \text{ V}, I_C = 2 \text{ mA}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	—	0.2	V	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$
Base to emitter voltage	V_{BE}	—	—	0.75	V	$V_{CE} = 12 \text{ V}, I_C = 2 \text{ mA}$

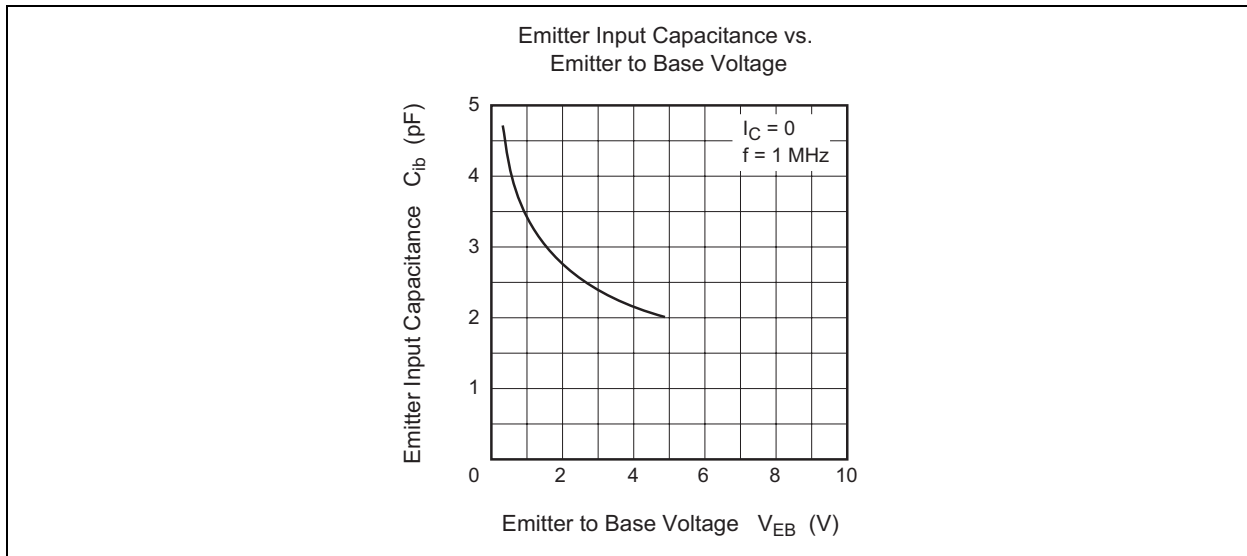
Notes: 1. The 2SC5850 is grouped by h_{FE} as follows.

Grade	B	C	D
Mark	LB	LC	LD
h_{FE}	100 to 200	160 to 320	250 to 500

EOL Product

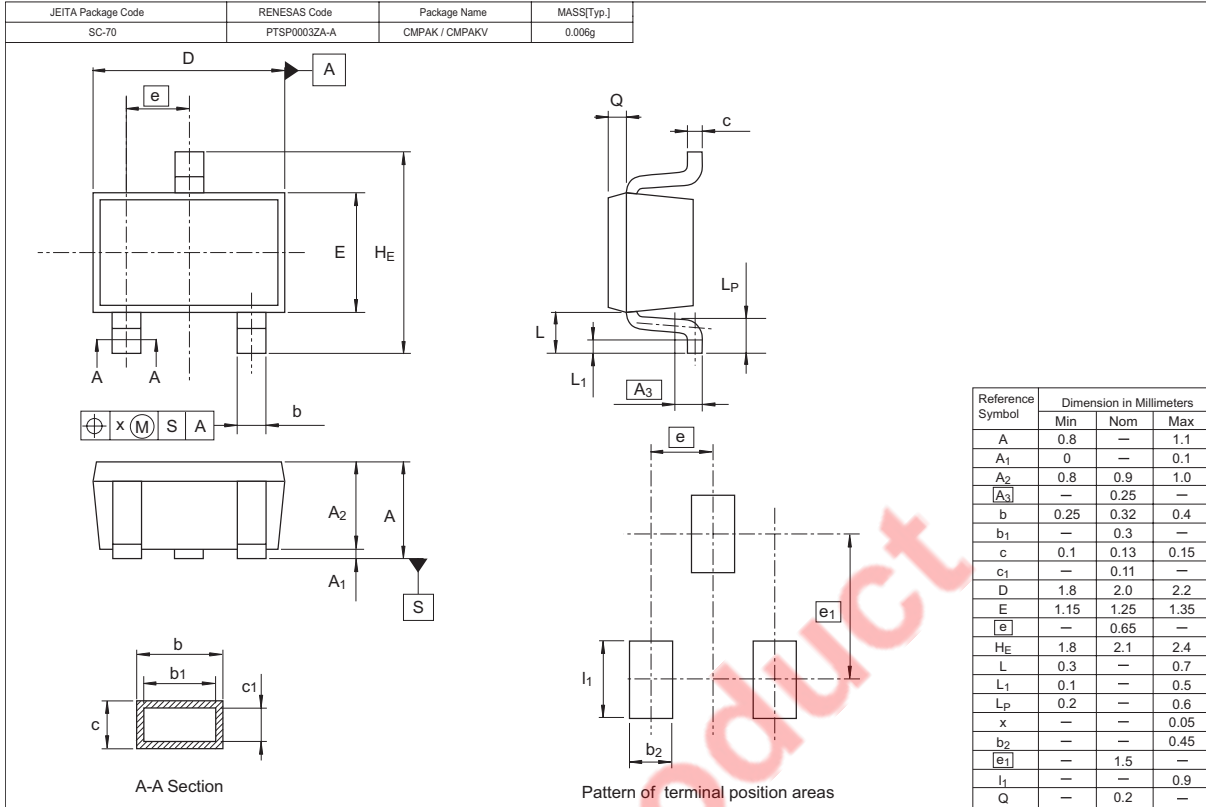
Main Characteristics





EOL Product

Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SC5850LBTL-E	3000	φ 178 mm Reel, 8 mm Emboss Taping
2SC5850LCTL-E		
2SC5850LDTL-E		

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

RENESAS Technology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

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